

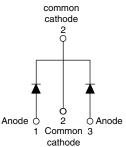
# VS-60CTQ150PbF, VS-60CTQ150-N3

**Vishay Semiconductors** 









PRODUCT SUMMARY					
Package	TO-220AB				
I <sub>F(AV)</sub>	2 x 30 A				
V <sub>R</sub>	150 V				
V <sub>F</sub> at I <sub>F</sub>	0.72 V				
I <sub>RM</sub> max.	20 mA at 125 °C				
T <sub>J</sub> max.	175 °C				
Diode variation	Common cathode				
E <sub>AS</sub>	0.4 mJ				

## **FEATURES**

- 175 °C T<sub>J</sub> operation
- · Low forward voltage drop
- · High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



- RoHS COMPLIANT HALOGEN FREE
- · Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC-JESD47
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

## DESCRIPTION

The VS-60CTQ150... center tap Schottky rectifier series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL CHARACTERISTICS VALUES UNITS								
I <sub>F(AV)</sub>	Rectangular waveform	60	A					
V <sub>RRM</sub>		150	V					
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	710	A					
V <sub>F</sub>	30 A <sub>pk</sub> , T <sub>J</sub> = 125 °C (typical, per leg)	0.69	V					
TJ	Range	- 55 to 175	°C					

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-60CTQ150PbF	VS-60CTQ150-N3	UNITS			
Maximum DC reverse voltage	V <sub>R</sub>	150	150	V			
Maximum working peak reverse voltage	V <sub>RWM</sub>	150	150	v			

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDI	TIONS	VALUES	UNITS			
Maximum average per l	° .	50 % duty cycle at $T_{C}$ = 137 °C, rectangular waveform		30				
See fig. 5 per devi	I <sub>F(AV)</sub>	$30\%$ duty cycle at $10^{\circ} = 137^{\circ}$ c	, rectangular wavelonn	60				
Maximum peak one cycle non-repetitive		5 $\mu s$ sine or 3 $\mu s$ rect. pulse	Following any rated load condition and	710	A			
surge current per leg See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	with rated V <sub>RRM</sub> applied	270				
Non-repetitive avalanche energy per leg	E <sub>AS</sub>	$T_{J} = 25 \text{ °C}, I_{AS} = 0.9 \text{ A}, L = 1 \text{ mH}$		0.4	mJ			
Repetitive avalanche current per leg	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ s Frequency limited by T <sub>J</sub> maximum V <sub>A</sub> = 1.5 x V <sub>R</sub> typical		0.9	А			

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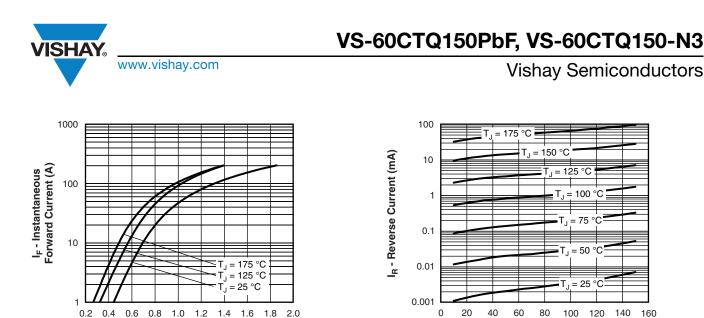
<b>ELECTRICAL SPECIF</b>	ICATIONS
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PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
Maximum forward voltage drop per leg See fig. 1		30 A	T.I = 25 °C	0.83	0.88	
	V (1)	60 A	- IJ=25 C	0.98	1.09	V
	V <sub>FM</sub> <sup>(1)</sup>	30 A	T 105.00	0.67	0.72	
		60 A	T <sub>J</sub> = 125 °C	0.82	0.87	
Maximum reverse leakage current per leg	I <sub>RM</sub>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	7	75	μA
See fig. 2		T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	7.2	20	mA
Typical junction capacitance per leg	CT	$V_R$ = 5 $V_{DC}$ (test signal range 100 kHz to 1 MHz) 25 °C		-	650	pF
Typical series inductance per leg	Ls	Measured lead to lead 5 mm from package body		-	7.5	nH
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	-	10 000	V/µs	

### Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,\,duty\,cycle$  < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range	)	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to 175	°C	
Maximum thermal resistance,	per leg	P	DC operation See fig. 4	1.2		
junction to case per package		R <sub>thJC</sub>	DC operation	0.6	°C/W	
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, smooth and greased	0.25	0,11	
Approximate weight				6	g	
Approximate weight				0.21	oz.	
minimum				6 (5)	kgf ⋅ cm	
Mounting torque	maximum			12 (10)	(lbf ⋅ in)	
Marking device			Case style TO-220AB	60CT	Q150	



V<sub>FM</sub> - Forward Voltage Drop (V) Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

V<sub>R</sub> - Reverse Voltage (V)

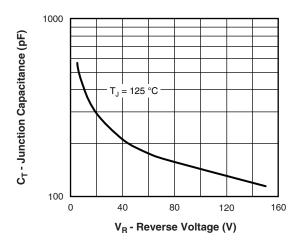


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

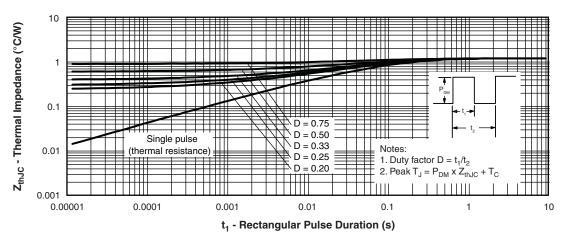
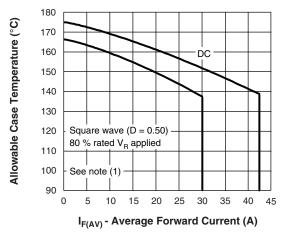


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

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Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

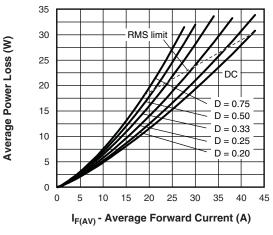


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

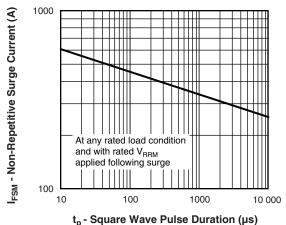


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

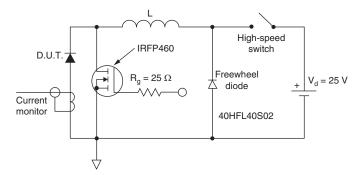


Fig. 8 - Unclamped Inductive Test Circuit

### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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## Vishay Semiconductors

## **ORDERING INFORMATION TABLE**

1							
Device code	VS-	60	С	Т	Q	150	PbF
I	1	2	3	4	5	6	7
1	-	Vishay	Semico	nductor	s produc	ct	
2	-	Curren	t rating (	60 = 60	A)		
3	-	Circuit	configur	ation			
		C = Co	mmon d	athode			
4	-	Packag	je				
		T = TO	-220				
5	-	Schottky "Q" series					
6	-	Voltage rating (150 = 150 V)					
7	-	Environmental digit					
		• PbF	= Lead	(Pb)-fre	e and R	oHS co	mpliant

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-60CTQ150PbF	50	1000	Antistatic plastic tube				
VS-60CTQ150-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95222					
Part marking information	TO-220AB PbF	www.vishay.com/doc?95225			
Part marking information	TO-220AB -N3	www.vishay.com/doc?95028			



**Vishay Semiconductors** 

**TO-220AB** 

### **DIMENSIONS** in millimeters and inches





.ead	assignments

**Diodes** 

1. - Anode/open 2. - Cathode 3. - Anode

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6

#### Notes

- <sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994
- <sup>(2)</sup> Lead dimension and finish uncontrolled in L1
- <sup>(3)</sup> Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- $^{\left( 4\right) }$  Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1

MILLIMETERS INCHES SYMBOL NOTES MIN. MAX. MIN. MAX. 10.51 0.414 10.11 0.398 3,6 Е E1 6.86 8.89 0.270 0.350 6 E2 0.76 0.030 7 --2.41 2.67 0.095 0.105 е 0.208 e1 4.88 5.28 0.192 H1 6.09 6.48 0.240 0.255 6,7 13.52 14.02 0.532 0.552 L L1 3.32 3.82 0.131 0.150 2 ØΡ 3.54 3.73 0.139 0.147 2.60 0.102 Q 3.00 0.118 90° to 93° 90° to 93° θ

Conforms to JEDEC outline TO-220AB

- (7) Dimensions E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC TO-220, except A2 (maximum) and D2 (minimum) where dimensions are derived from the actual package outline



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